
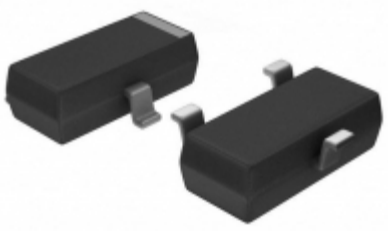






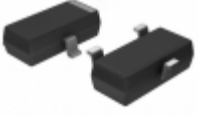

	<h2>SI2351DS-T1-E3</h2>
	<p><b>Hersteller-Teilenummer:</b> SI2351DS-T1-E3</p> <p><b>Hersteller / Marke:</b> Electro-Films (EFI) / Vishay</p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 20V 2.8A SOT23-3</p> <p><b>Datenblätter:</b>  <a href="#">SI2351DS-T1-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 88644 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SI2351DS-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET P-CH 20V 2.8A SOT23-3
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	88644 pcs Stock
detaillierte Beschreibung	P-Channel 20V 2.8A (Tc) 1W (Ta), 2.1W (Tc) Surface
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1W (Ta), 2.1W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	2.8A (Tc)
Rds On (Max) @ Id, Vgs	115 mOhm @ 2.4A, 4.5V
VGS (th) (Max) @ Id	1.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	5.1nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	250pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	2.5V, 4.5V
Vgs (Max)	±12V
Verpackung	Original-Reel®
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI2351DS-T1-E3DKR





SI2351DS-T1-E3 ist neu im Original, Suche SI2351DS-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2351DS-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI2351DS-T1-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI2350DS</b> VISHAY SI2350DS VISHAY</p>	 <p><b>SI2347DS-T1-GE3</b> Vishay / Siliconix MOSFET P-CH 30V 5A SOT-23</p>	 <p><b>SI2351DS-T1-E3</b> Vishay / Siliconix MOSFET P-CH 20V 2.8A SOT23-3</p>	 <p><b>SI2347DS-T1-E3</b> VISHAY SI2347DS-T1-E3 VISHAY</p>
 <p><b>SI2347DS-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 30V 5A SOT-23</p>	 <p><b>SI2351DS</b> Vishay Precision Group SI2351DS VISHAY</p>	 <p><b>SI2356DS-T1-GE3</b> Vishay / Siliconix MOSFET N-CH 40V 4.3A SOT-23</p>	 <p><b>SI2356DS-T1-E3</b> VISHAY VISHAY SOT-23</p>

### heiße Teile

Mehr

 SI2337DS-T1-GE3	 SI2337DS-T1-GE3	 SI2338DS-T1-E3	 SI2338DS-T1-GE3	 SI2338DS-T1-GE3
 SI2341DS	 SI2341DS-T1-E3	 SI2341DS-T1-E3	 SI2341DS-T1-GE3	 SI2341DS-T1-GE3
 SI2342DS-T1-E3	 SI2342DS-T1-GE3	 SI2342DS-T1-GE3	 SI2343ADS-T1-GE3	 SI2343CDS
 SI2343CDS-T1-E3	 SI2343CDS-T1-GE3	 SI2343CDS-T1-GE3	 SI2343DS-T1-E3	 SI2343DS-T1-E3
 SI2343DS-T1-GE3	 SI2343DS-T1-GE3	 SI2344DS-E3	 SI2347DS-T1-GE3	 SI2347DS-T1-GE3
 SI2351DS-T1-E3	 SI2351DS-T1-GE3	 SI2351DS-T1-GE3	 SI2356DS-T1-GE3	 SI2356DS-T1-GE3
 SI2365EDS	 SI2365EDS-T1-GE3	 SI2365EDS-T1-GE3	 SI2366DS-T1-E3	 SI2366DS-T1-GE
 SI2366DS-T1-GE3	 SI2366DS-T1-GE3	 SI2367DS-T1-E3	 SI2367DS-T1-GE3	 SI2367DS-T1-GE3
 SI2369DS-T1-GE3	 SI2369DS-T1-GE3	 SI2371EDS-T1-GE3	 SI2371EDS-T1-GE3	 SI2372DS-T1-E3
 SI2372DS-T1-GE3	 SI2372DS-T1-GE3	 SI2374DS-T1-GE3	 SI2374DS-T1-GE3	 SI2377DS-T1-GE3

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